

7N65A

Power MOSFET

7A, 650V N-CHANNEL POWER MOSFET

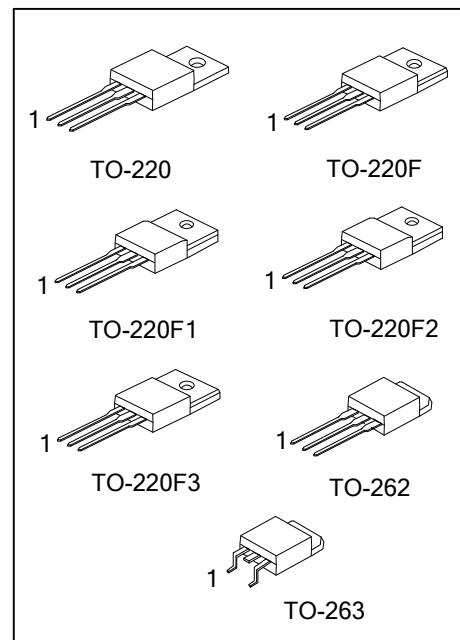
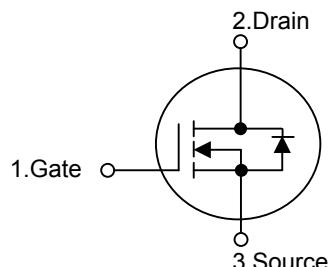
■ DESCRIPTION

The UTC 7N65A is a high voltage N-Channel enhancement mode power field effect transistors designed to have minimize on-state resistance, superior switching performance and withstand high energy pulse in the avalanche and commutation mode. This power MOSFET is well suited for high efficiency switch mode power supply.

■ FEATURES

- * $R_{DS(ON)} \leq 1.4\Omega$ @ $V_{GS}=10V$, $I_D=3.5A$
- * Fast switching capability
- * Avalanche energy tested
- * Improved dv/dt capability, high ruggedness

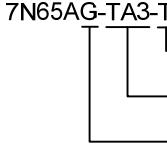
■ SYMBOL



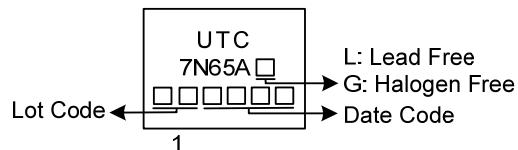
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
7N65AL-TA3-T	7N65AG-TA3-T	TO-220	G	D	S	Tube
7N65AL-TF3-T	7N65AG-TF3-T	TO-220F	G	D	S	Tube
7N65AL-TF1-T	7N65AG-TF1-T	TO-220F1	G	D	S	Tube
7N65AL-TF2-T	7N65AG-TF2-T	TO-220F2	G	D	S	Tube
7N65AL-TF3T-T	7N65AG-TF3T-T	TO-220F3	G	D	S	Tube
7N65AL-T2Q-T	7N65AG-T2Q-T	TO-262	G	D	S	Tube
7N65AL-TQ2-T	7N65AG-TQ2-T	TO-263	G	D	S	Tube
7N65AL-TQ2-R	7N65AG-TQ2-R	TO-263	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

 7N65AG-TA3-T	(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TF3: TO-220F, TF1: TO-220F1 TF2: TO-220F2, TF3T: TO-220F3, T2Q: TO-262, TQ2: TO-263 (3) G: Halogen Free and Lead Free, L: Lead Free
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■ MARKING



■ ABSOLUTE MAXIMUM RATING ($T_c=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	650	V
Gate-Source Voltage		V_{GSS}	± 30	V
Drain Current	Continuous	I_D	7	A
	Pulsed (Note 2)	I_{DM}	28	A
Avalanche Energy (Note 3)	Single Pulsed (Note 3)	E_{AS}	145	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	3.3	V/ns
Power Dissipation	TO-220/TO-262	P_D	65	W
	TO-263		30	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature Range		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature

3. $L = 10\text{mH}$, $I_{AS} = 5.4\text{A}$, $V_{DD}=50\text{V}$, $R_G = 27 \Omega$, Starting $T_J = 25^\circ\text{C}$

4. $I_{SD} \leq 7.0\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT
Junction to Ambient	TO-220/TO-262 TO-263	θ_{JA}	83.3	$^\circ\text{C/W}$
	TO-220F/TO-220F1 TO-220F2/TO-220F3		62.5	$^\circ\text{C/W}$
Junction to Case	TO-220/TO-262 TO-263	θ_{JC}	1.92	$^\circ\text{C/W}$
	TO-220F/TO-220F1 TO-220F2/TO-220F3		4.16	$^\circ\text{C/W}$

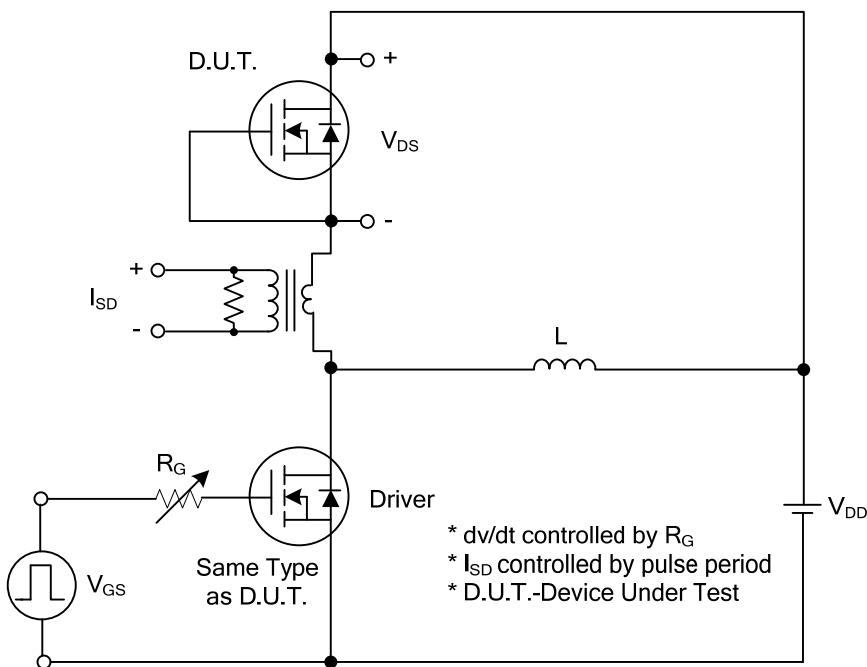
■ ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	650			V
Drain-Source Leakage Current	I_{DSS}	$V_{\text{DS}}=650\text{V}, V_{\text{GS}}=0\text{V}$		10		μA
Gate-Source Leakage Current	Forward	$V_{\text{GS}}=30\text{V}, V_{\text{DS}}=0\text{V}$		100		nA
	Reverse	$V_{\text{GS}}=-30\text{V}, V_{\text{DS}}=0\text{V}$		-100		nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{\text{GS}(\text{TH})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=3.5\text{A}$		1.05	1.4	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{ISS}	$V_{\text{DS}}=25\text{V}, V_{\text{GS}}=0\text{V}, f=1.0 \text{ MHz}$		1630		pF
Output Capacitance	C_{OSS}			117		pF
Reverse Transfer Capacitance	C_{RSS}			12.5		pF
SWITCHING CHARACTERISTICS						
Total Gate Charge	Q_G	$V_{\text{DS}}=100\text{V}, V_{\text{GS}}=10\text{V}, I_{\text{D}}=7.0\text{A}$ $I_G=1\text{mA}$ (Note 1, 2)		50		nC
Gate-Source Charge	Q_{GS}			8		nC
Gate-Drain Charge	Q_{GD}			8		nC
Turn-On Delay Time	$t_{\text{D}(\text{ON})}$	$V_{\text{DD}}=100\text{V}, V_{\text{GS}}=10\text{V}, I_{\text{D}}=7.0\text{A}$ $R_G=25\Omega$ (Note 1, 2)		19		ns
Turn-On Rise Time	t_R			16.5		ns
Turn-Off Delay Time	$t_{\text{D}(\text{OFF})}$			130		ns
Turn-Off Fall Time	t_F			43.8		ns
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
Maximum Body-Diode Continuous Current	I_S				7	A
Maximum Body-Diode Pulsed Current	I_{SM}				28	A
Drain-Source Diode Forward Voltage	V_{SD}	$V_{\text{GS}}=0\text{V}, I_S=7\text{A}$			1.4	V
Reverse Recovery Time	t_{rr}	$V_{\text{GS}}=0\text{V}, I_S=7\text{A},$ $dI_F/dt=100\text{A}/\mu\text{s}$ (Note1)		280		ns
Reverse Recovery Charge	Q_{rr}			3		μC

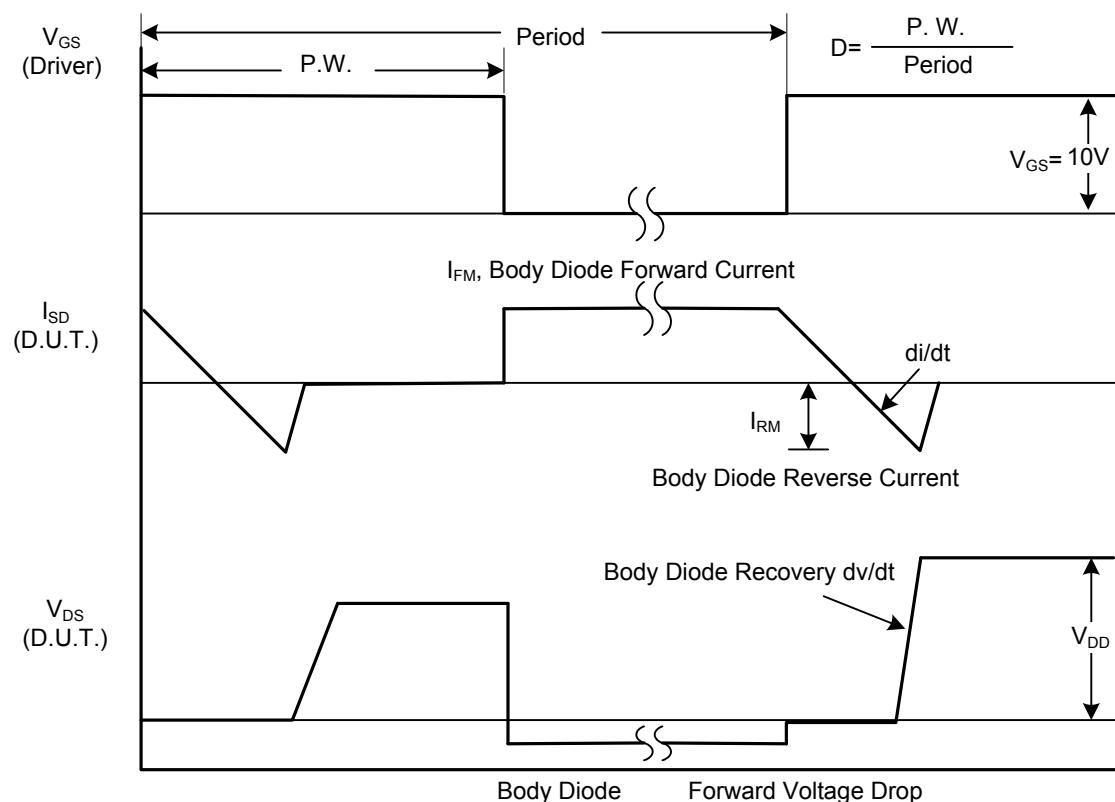
Notes: 1. Pulse Test : Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$.

2. Essentially independent of operating ambient temperature.

■ TEST CIRCUITS AND WAVEFORMS

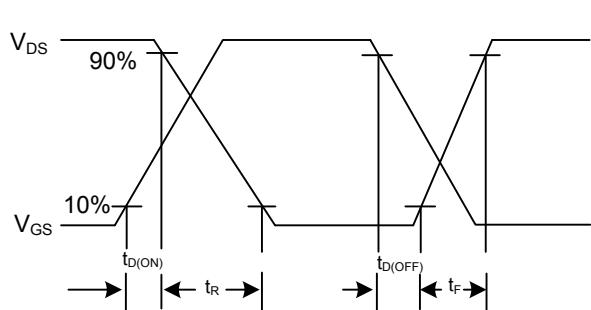
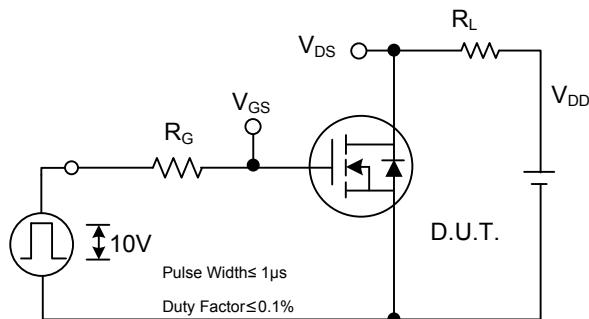


Peak Diode Recovery dv/dt Test Circuit



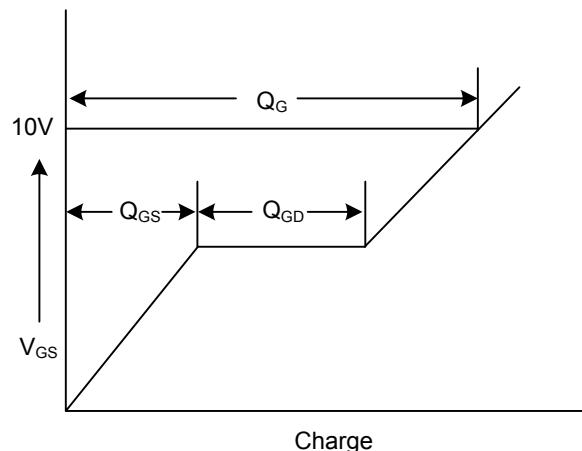
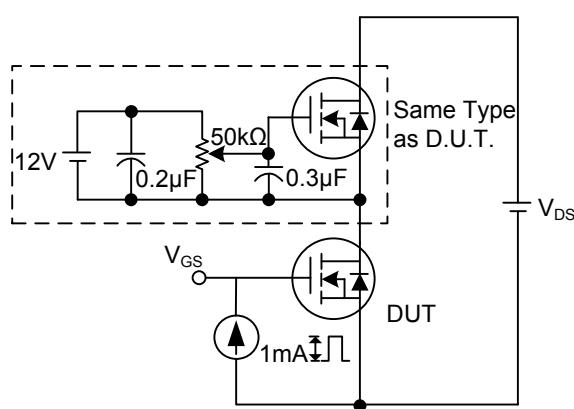
Peak Diode Recovery dv/dt Waveforms

■ TEST CIRCUITS AND WAVEFORMS (Cont.)



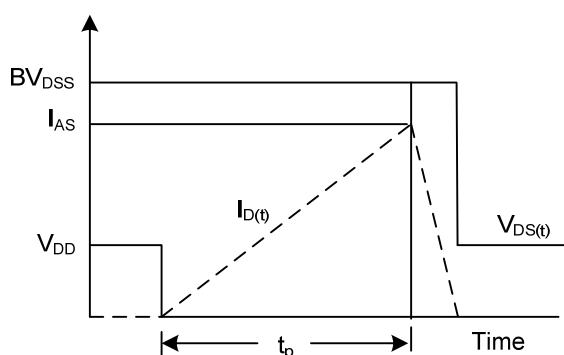
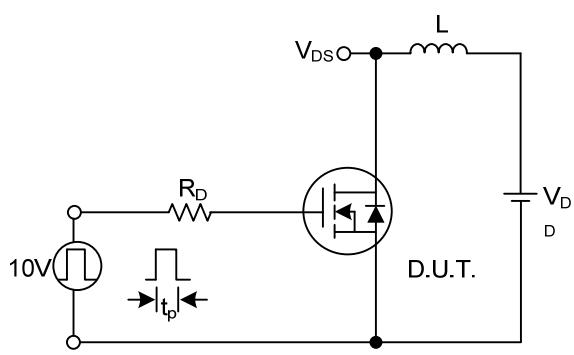
Switching Test Circuit

Switching Waveforms



Gate Charge Test Circuit

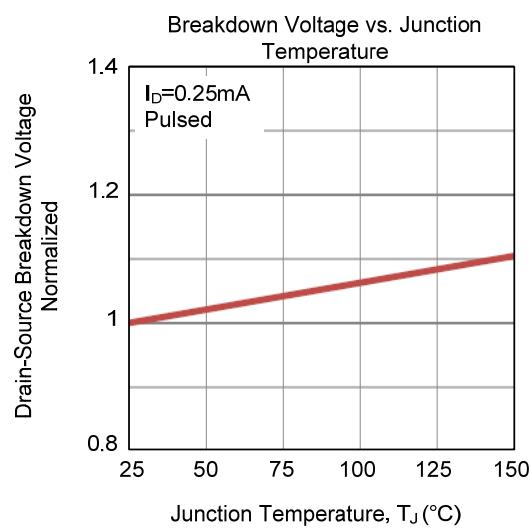
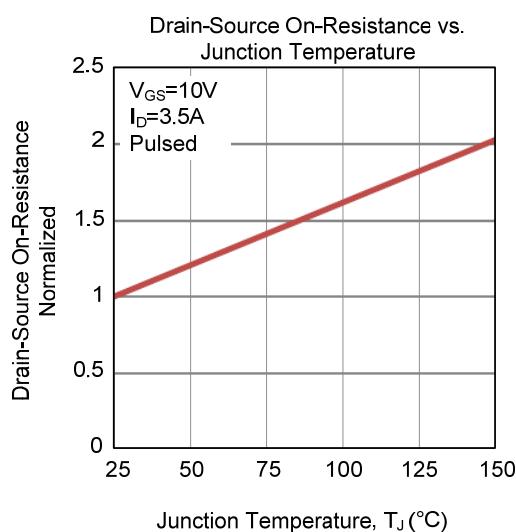
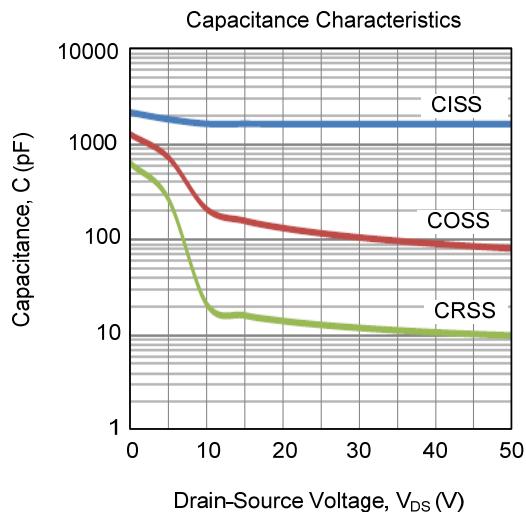
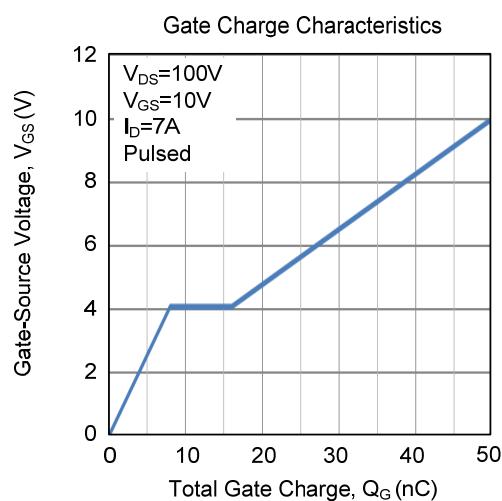
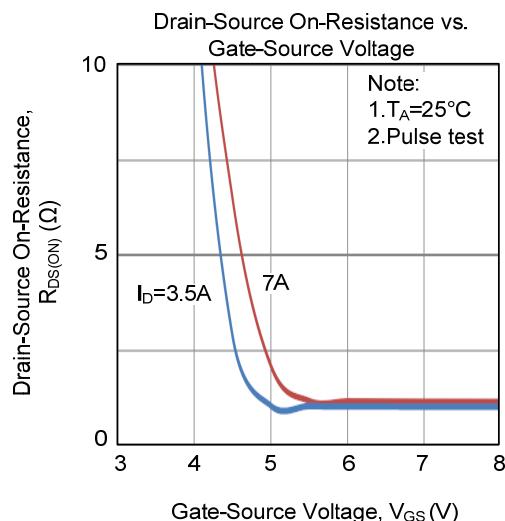
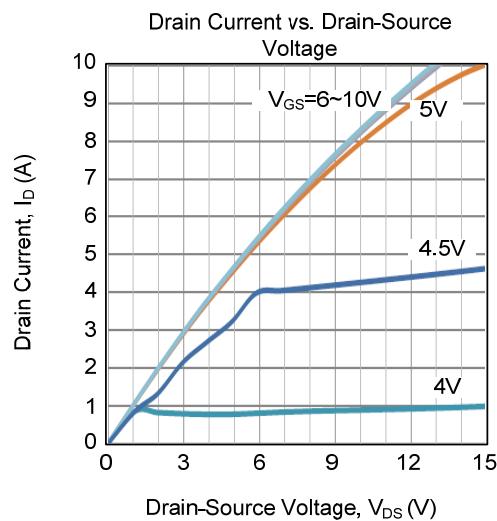
Gate Charge Waveform



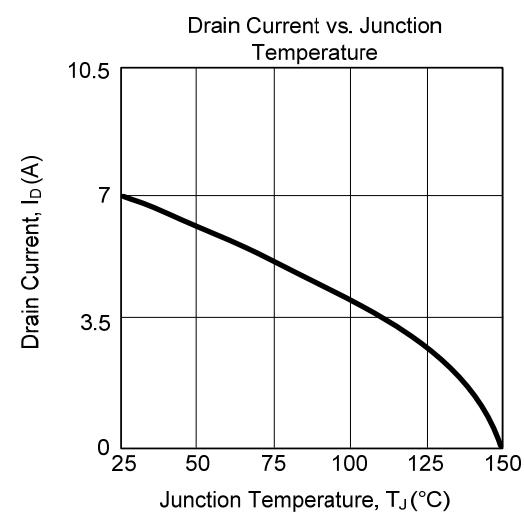
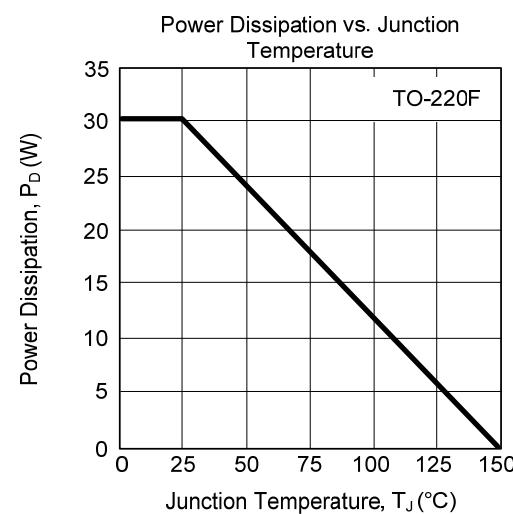
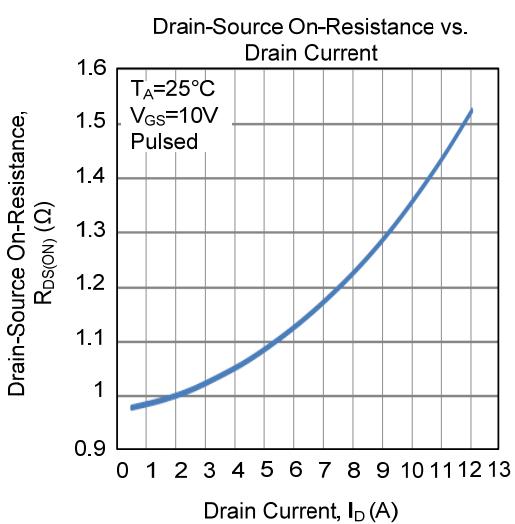
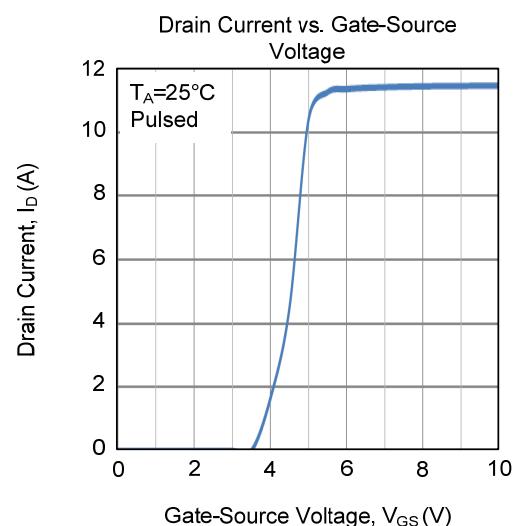
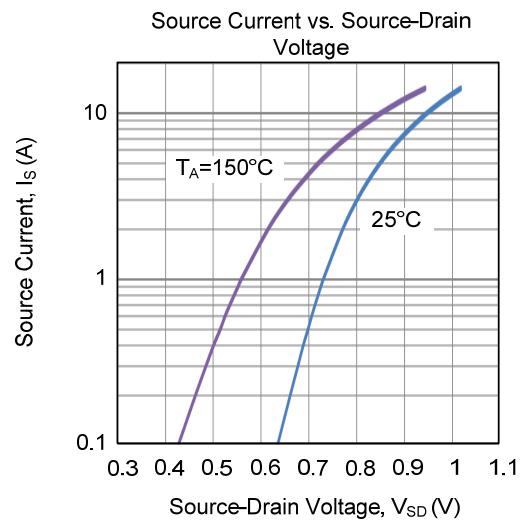
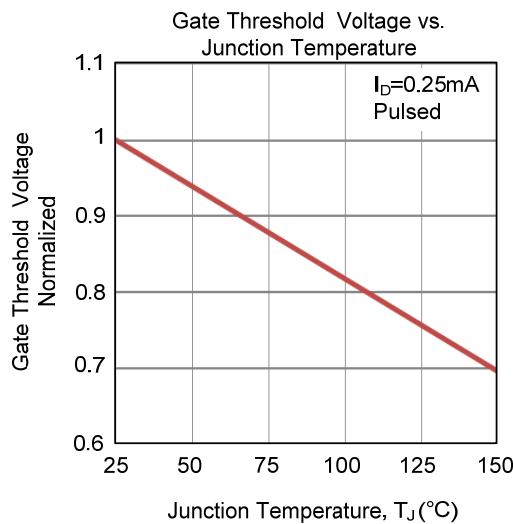
Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

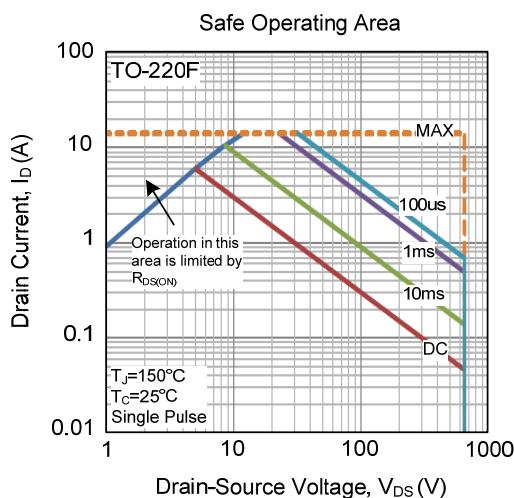
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



- TYPICAL CHARACTERISTICS (Cont.)



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